High-Frequency Amplifier Transistor (11V, 50mA, 3.2GHz)

2SC5662 / 2SC4726H / 2SC4726 / 2SC4083 / 2SC3838K / 2SC4043S

Features

- 1) High transition frequency. (Typ. ft= 1.5GHz)
- 2) Small rbb'·Cc and high gain. (Typ. 4ps)
- 3) Small NF.

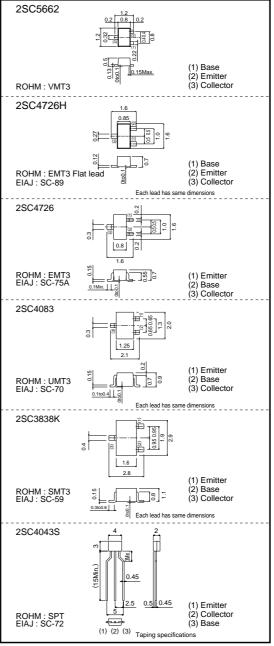
• Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit	
Collector-base voltage		Vсво	20	V	
Collector-emitter voltage		Vceo	11	V	
Emitter-base voltage		VEBO	3	V	
Collector current		lc	50	mA	
Collector power dissipation	2SC5662,2SC4726H, 2SC4726	_	0.15	w	
	2SC4083,2SC3838K	Pc	0.2		
	2SC4043S		0.3		
Junction temperature		Tj	150	°C	
Storage temperature		Tstg	-55~+150	°C	

● Packaging specifications and hFE

Type	2SC5662	2SC4726H	2SC4726	2SC4083	2SC3838K	2SC4043S
Package	VMT3	EMT3H	EMT3	UMT3	SMT3	SPT
hre	NP	NP	NP	NP	NP	P
Marking	AD	AD	AD	1D	AD	-
Code	T2L	T2L	TL	T106	T146	TP
Basic ordering unit (pieces)	8000	8000	3000	3000	3000	5000

●External dimensions (Units : mm)



● **Absolute maximum ratings** (Ta = 25°C)

Parameter		Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-base breakdown voltage		ВУсво	20	-	-	V	Ic = 10μA	
Collector-emitter breakdown voltage		BVceo	11	-	-	V	Ic = 1mA	
Emitter-base breakdown voltage		BVEBO	3	-	-	V	Ιε = 10μΑ	
Collector cutoff current		Ісво	-	-	0.5	μΑ	VcB = 10V	
Emitter cutoff current		Ієво	-	-	0.5	μΑ	VEB = 2V	
Collector-emitter saturation voltage		VCE(sat)	-	-	0.5	V	Ic/IB = 10mA/5mA	
	2SC5662,2SC4726H, 2SC4726,2SC4083, 2SC3838K	hre	56	-	180	-	Vce/Ic = 10V/5mA	
	2SC4043S		82	-	180	1		
Transition frequ	uency	fτ	1.4	3.2	-	GHz	Vce = 10V , Ie = 10mA , f = 500MHz	
Output capacitance		Cob	-	0.8	1.5	pF	Vcb = 10V , IE = 0A , f = 1MHz	
Collector-base time constant		rbb'-Cc	-	4	12	ps	Vcs = 10V , Ic = 10mA , f = 31.8MHz	
Noise factor		NF	-	3.5	-	dB	$V_{CE} = 6V$, $I_{C} = 2mA$, $f = 500MHz$, $Rg = 50\Omega$	